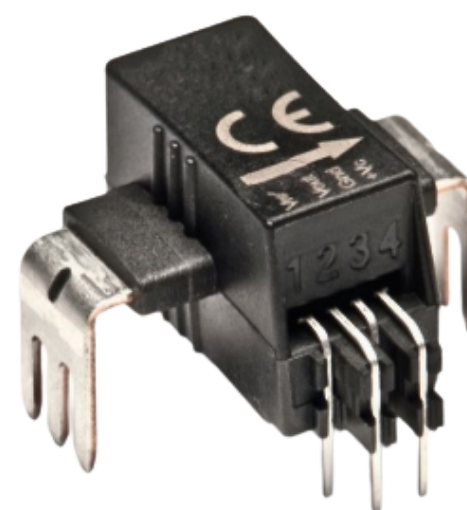


## Automotive Current Sensor ASIC Chip Series

### YC10..120LSR5



Suitable for measuring DC, AC, and pulse currents; the primary and secondary circuits are completely isolated, with no insertion loss.

Product Model	Rated Current IpN(A)	Max Measurement Range IpM(A)	Sensitivity G(mV/A)	Rated Output Vout(V)
YCOV10LSR5	10	± 25	80	0.8
YCOV16LSR5	16	± 40	50	0.8
YCOV20LSR5	20	± 50	40	0.8
YCOV32LSR5	32	± 80	25	0.8
YCOV40LSR5	40	± 100	20	0.8
YCOV50LSR5	50	± 125	16	0.8
YCOV80LSR5	80	± 200	10	0.8
YCOV100LSR5	100	± 250	8	0.8
YCOV120LSR5	120	± 300	6.67	0.8

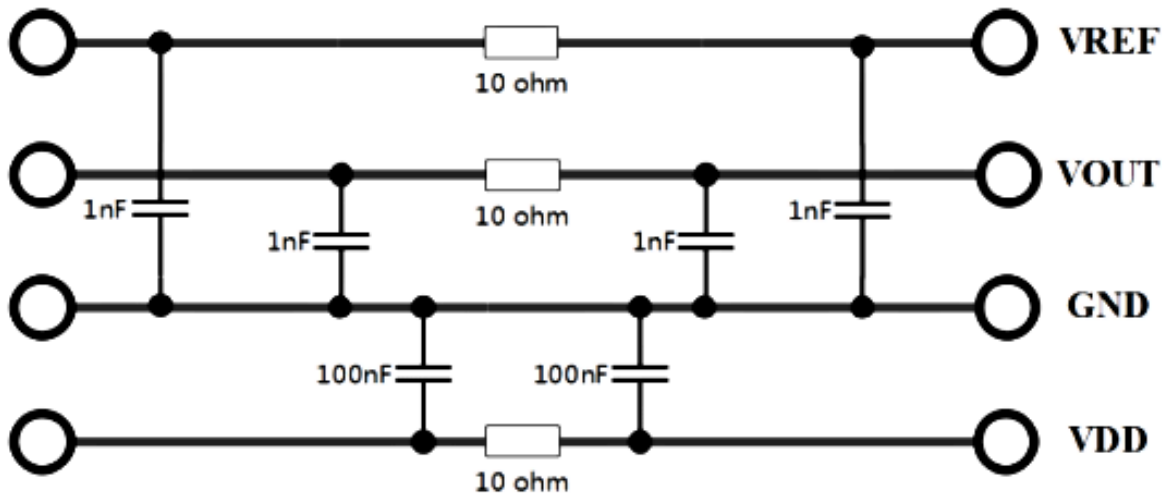
Application Fields
• Servo Motors
• Battery Supply Applications
• Uninterruptible Power Supplies (UPS)
• Solar Controllers
• Welding Machine Power Applications

Parameter	Symbol	Unit	Min	Standard	Max
Operating Temperature Range		° C	-40		105
Storage Temperature Range		° C	-40		105

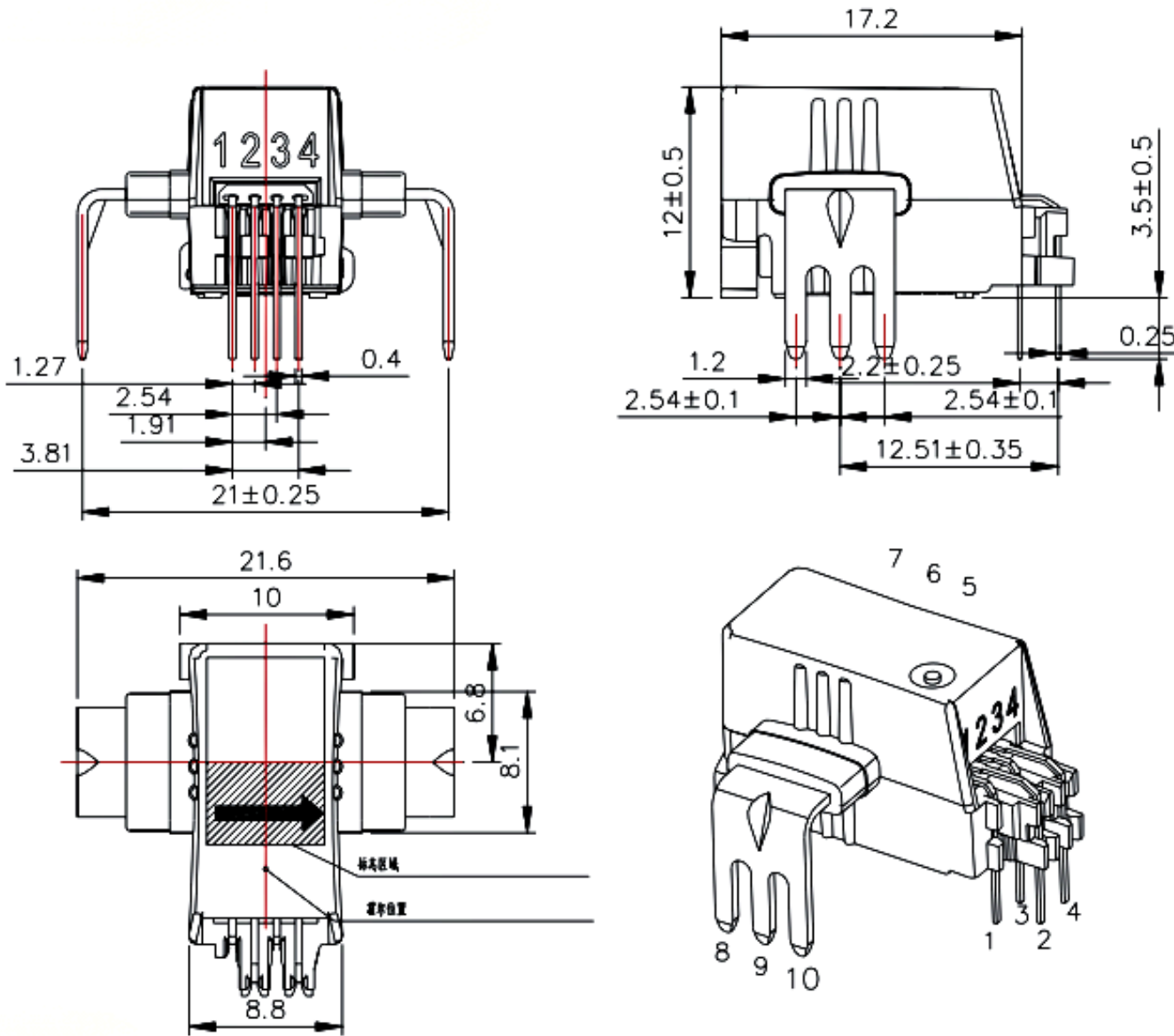
### Executive Standards

- JB/T 7490-2007 Hall Effect Current Sensors
- SJ20790-2000 General Specification for Current and Voltage Sensors

### Application Circuit

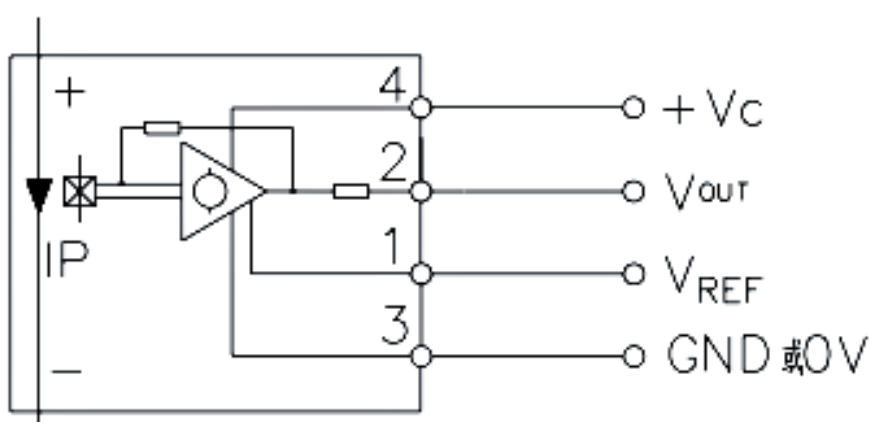


### Outline Dimensions and Pin Definition (Unit: mm)

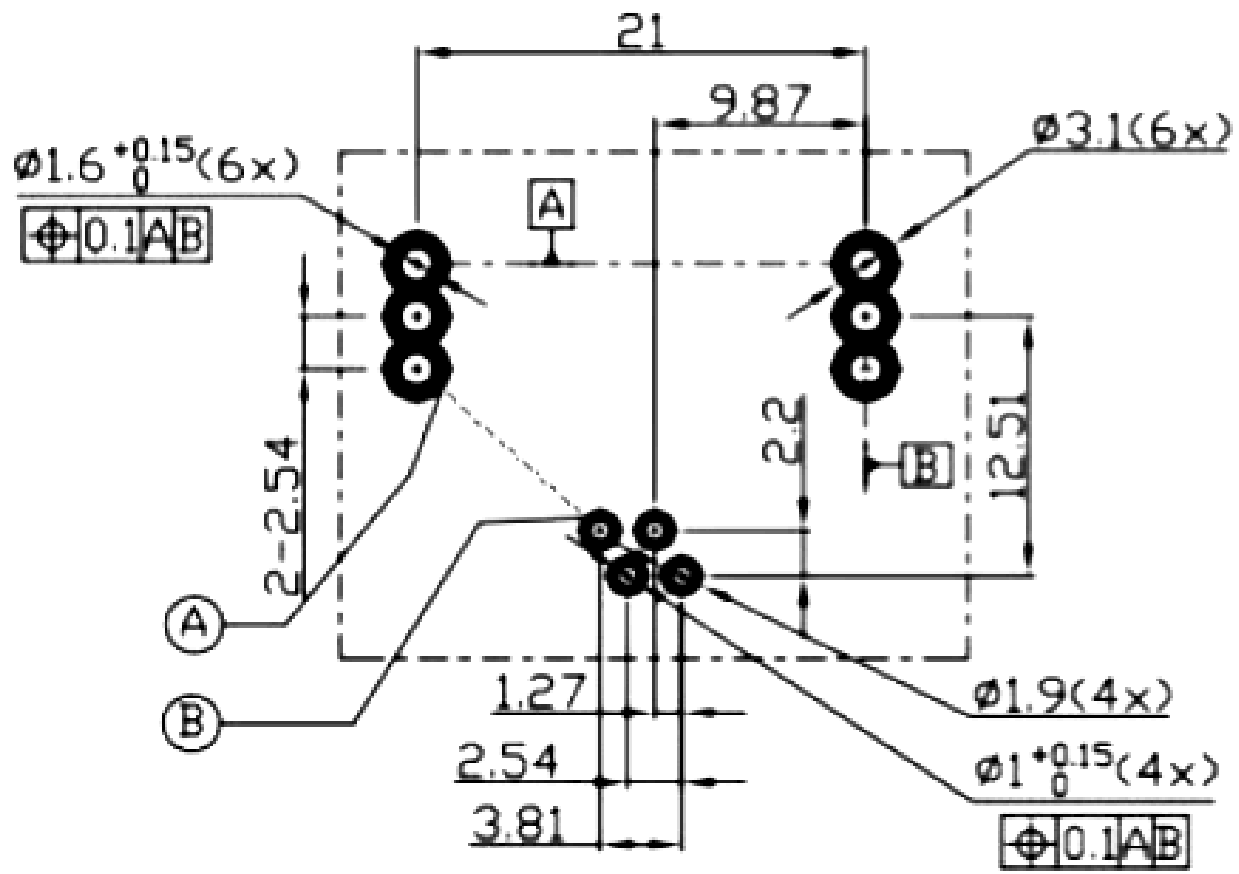


Pin Definition		
1	VREF	Reference Voltage Output
2	VOUT	Output Pin
3	GND	Ground
4	+Vc	DC +5V
5, 6, 7	I+	Input Current Positive
8, 9, 10	I-	Input Current Negative

### Schematic Example



PCB Dimension Drawing



	$d_{CI}$ (mm)	$d_{CP}$ (mm)
A-B	9.42	9.42

YC0V10LSR5 Electrical Parameters @25°C, Vcc=5V, RL=10KΩ

Parameter	Symbol	Unit	Min	Typ	Max	Remarks
Nominal Input Current	IPN	A		10		
Max Measurable Current	IPM	A	-25		25	Vcc > 4.6V
Overcurrent Copper Resistance	RP	mΩ		0.22		@TA=25 ° C
Supply Voltage	Vcc	V	4.5	5	5.5	
Power Consumption Current	IC	mA		8	10	
Reference Voltage Output	Vref	V	2.48	2.5	2.52	
Output Voltage Range	Vout - Vref	V	-2		2	
Quiescent Output @IP=0	VOE	mV	-5		5	Vout-Vref @ Vref=2.5V
Reference Voltage Temp Drift	TCVref	ppm/ ° C	-170		170	-40 ° C to 105 ° C
Quiescent Output Temp Drift	TCG	mV/ ° C	-0.075		0.075	-40 ° C to 105 ° C
Nominal Sensitivity	Gth	mV/A		80		800mV@IPN
Sensitivity Error	ε G	%	-0.5		0.5	
Sensitivity Temp Drift @G	TCG	ppm/ ° C	-200		200	
Linearity 0-IPN	ε L	% of	-0.4		0.4	@0-IPN
Remanent Magnetism	IOM	A	-0.2		0.2	
Response Time 90% of IPN	tr	μ s			2.5	@50A/μ s
Bandwidth (-3dB)	BW	kHz		250		
Accuracy @ IPN @TA=25 ° C	X	% of IPN	-1		1	
Accuracy @ IPN @TA=-40-105 ° C	X	% of IPN	-2.5		2.5	
Insulation Voltage	KV			2		
Overcurrent Copper Working Temp	° C				120	

**YC0V16LSR5 Electrical Parameters @25°C, Vcc=5V, RL=10KΩ**

Parameter	Symbol	Unit	Min	Typ	Max	Remarks
Nominal Input Current	IPN	A		16		
Max Measurable Current	IPM	A	-40		40	VCC > 4.6V
Overcurrent Copper Resistance	RP	mΩ		0.22		@TA=25 ° C
Supply Voltage	VCC	V	4.5	5	5.5	
Power Consumption Current	IC	mA		8	10	
Reference Voltage Output	Vref	V	2.48	2.5	2.52	
Output Voltage Range	Vout - Vref	V	-2		2	
Quiescent Output @IP=0	VOE	mV	-5		5	Vout-Vref @
Reference Voltage Temp Drift	TCVref	ppm/ ° C	-170		170	-40 ° C to 105 ° C
Quiescent Output Temp Drift	TCG	mV/ ° C	-0.075		0.075	-40 ° C to 105 ° C
Nominal Sensitivity	Gth	mV/A		50		800mV@IPN
Sensitivity Error	ε G	%	-0.5		0.5	
Sensitivity Temp Drift @G	TCG	ppm/ ° C	-200		200	
Linearity 0-IPN	ε L	% of	-0.4		0.4	@0-IPN
Remanence	IOM	A	-0.2		0.2	
Response Time 90% of IPN	tr	μs			2.5	@50A/μs
Bandwidth (-3dB)	BW	kHz		250		
Accuracy @ IPN @TA=25 ° C	X	% of IPN	-1		1	
Accuracy @ IPN @TA=-40~105 ° C	X	% of IPN	-2.5		2.5	
Insulation Voltage	KV			2		
Overcurrent Busbar Operating Temp	° C				120	

**YC0V20LSR5 Electrical Parameters @25°C, Vcc=5V, RL=10KΩ**

Parameter	Symbol	Unit	Min	Typ	Max	Remarks
Nominal Input Current	IPN	A		20		
Max Measurable Current	IPM	A	-50		50	VCC > 4.6V
Overcurrent Copper Resistance	RP	mΩ		0.22		@TA=25 ° C
Supply Voltage	VCC	V	4.5	5	5.5	
Power Consumption Current	IC	mA		8	10	
Reference Voltage Output	Vref	V	2.48	2.5	2.52	
Output Voltage Range	Vout - Vref	V	-2		2	
Quiescent Output @IP=0	VOE	mV	-5		5	Vout-Vref @ Vref=2.5V
Reference Voltage Temp Drift	TCVref	ppm/ ° C	-170		170	-40 ° C to 105 ° C
Quiescent Output Temp Drift	TCVOE	mV/ ° C	-0.075		0.075	-40 ° C to 105 ° C
Nominal Sensitivity	Gth	mV/A		40		800mV@IPN
Sensitivity Error	ε G	%	-0.5		0.5	
Sensitivity Temp Drift @G	TCG	ppm/ ° C	-200		200	
Linearity 0-IPN	ε L	% of	-0.4		0.4	@0-IPN
Remanence	IOM	A	-0.2		0.2	
Response Time 90% of IPN	tr	μ s			2.5	@50A/μ s
Bandwidth (-3dB)	BW	kHz		250		
Accuracy @ IPN @TA=25 ° C	X	% of IPN	-1		1	
Accuracy @ IPN @TA=-40-105 ° C	X	% of IPN	-2.5		2.5	
Insulation Voltage	KV			2		
Overcurrent Copper Operating Temp	° C				120	

**YC0V32LSR5 Electrical Parameters @25°C, Vcc=5V, RL=10KΩ**

Parameter	Symbol	Unit	Min	Typ	Max	Remarks
Nominal Input Current	IPN	A		32		
Max Measurable Current	IPM	A	-80		80	VCC > 4.6V
Overcurrent Copper Resistance	RP	mΩ		0.22		@TA=25 ° C
Supply Voltage	VCC	V	4.5	5	5.5	
Power Consumption Current	IC	mA		8	10	
Reference Voltage Output	Vref	V	2.48	2.5	2.52	
Output Voltage Range	Vout - Vref	V	-2		2	
Quiescent Output @IP=0	VOE	mV	-5		5	Vout-Vref @ Vref=2.5V
Reference Voltage Temp Drift	TCVref	ppm/ ° C	-170		170	-40 ° C to 105 ° C
Quiescent Output Temp Drift	TCVOE	mV/ ° C	-0.075		0.075	-40 ° C to 105 ° C
Nominal Sensitivity	Gth	mV/A		25		800mV@IPN
Sensitivity Error	ε G	%	-0.5		0.5	
Sensitivity Temp Drift @G	TCG	ppm/ ° C	-200		200	
Linearity 0-IPN	ε L	% of	-0.4		0.4	@0-IPN
Remanence (Magnetic Offset)	IOM	A	-0.2		0.2	
Response Time 90% of IPN	tr	μ s			2.5	@50A/μ s
Bandwidth (-3dB)	BW	kHz		250		
Accuracy @ IPN @TA=25 ° C	X	% of IPN	-1		1	
Accuracy @ IPN @TA=-40-105 ° C	X	% of IPN	-2.5		2.5	
Insulation Voltage	KV			2		
Operating Temperature (Copper Bar)	° C				120	

**YC0V40LSR5 Electrical Parameters @25°C, Vcc=5V, RL=10KΩ**

Parameter	Symbol	Unit	Min	Typ	Max	Remarks
Nominal Input Current	IPN	A		40		
Max Measurable Current	IPM	A	-100		100	VCC > 4.6V
Overcurrent Copper Resistance	RP	mΩ		0.22		@TA=25 ° C
Supply Voltage	VCC	V	4.5	5	5.5	
Power Consumption Current	IC	mA		8	10	
Reference Voltage Output	Vref	V	2.48	2.5	2.52	
Output Voltage Range	Vout -Vref	V	-2		2	
Quiescent Output @IP=0	VOE	mV	-5		5	Vout-Vref @ Vref=2.5V
Reference Voltage Temp Drift	TCVref	ppm/ ° C	-170		170	-40 ° C to 105 ° C
Quiescent Output Temp Drift	TCVOE	mV/ ° C	-0.075		0.075	-40 ° C to 105 ° C
Nominal Sensitivity	Gth	mV/A		20		800mV@IPN
Sensitivity Error	ε G	%	-0.5		0.5	
Sensitivity Temp Drift @G	TCG	ppm/ ° C	-200		200	
Linearity 0-IPN	ε L	% of	-0.4		0.4	@0-IPN
Remanence	IOM	A	-0.2		0.2	
Response Time 90% of IPN	tr	μ s			2.5	@50A/μ s
Bandwidth (-3dB)	BW	kHz		250		
Accuracy @ IPN @TA=25 ° C	X	% of IPN	-1		1	
Accuracy @ IPN @TA=-40-105 ° C	X	% of IPN	-2.5		2.5	
Insulation Voltage	KV			2		
Overcurrent Copper Operating Temp	° C				120	

**YC0V50LSR5 Electrical Parameters @25°C, Vcc=5V, RL=10KΩ**

Parameter	Symbol	Unit	Min	Typ	Max	Remarks
Nominal Input Current	IPN	A		50		
Max Measurable Current	IPM	A	-125		125	VCC > 4.6V
Overcurrent Copper Resistance	RP	mΩ		0.22		@TA=25 ° C
Supply Voltage	VCC	V	4.5	5	5.5	
Power Consumption Current	IC	mA		8	10	
Reference Voltage Output	Vref	V	2.48	2.5	2.52	
Output Voltage Range	Vout - Vref	V	-2		2	
Quiescent Output @IP=0	VOE	mV	-5		5	Vout-Vref @ Vref=2.5V
Reference Voltage Temp Drift	TCVref	ppm/ ° C	-170		170	-40 ° C to 105 ° C
Quiescent Output Temp Drift	TCVOE	mV/ ° C	-0.075		0.075	-40 ° C to 105 ° C
Nominal Sensitivity	Gth	mV/A		16		800mV@IPN
Sensitivity Error	ε G	%	-0.5		0.5	
Sensitivity Temp Drift @G	TCG	ppm/ ° C	-200		200	
Linearity 0-IPN	ε L	% of	-0.4		0.4	@0-IPN
Remanence	IOM	A	-0.2		0.2	
Response Time 90% of IPN	tr	μ s			2.5	@50A/μ s
Bandwidth (-3dB)	BW	kHz		250		
Accuracy @ IPN @TA=25 ° C	X	% of IPN	-1		1	
Accuracy @ IPN @TA=-40-105 ° C	X	% of IPN	-2.5		2.5	
Insulation Voltage	KV			2		
Overcurrent Copper Operating Temp	° C				120	

**YC0V80LSR5 Electrical Parameters @25°C, Vcc=5V, RL=10KΩ**

Parameter	Symbol	Unit	Min	Typ	Max	Remarks
Nominal Input Current	IPN	A		80		
Max Measurable Current	IPM	A	-200		200	VCC > 4.6V
Overcurrent Copper Resistance	RP	mΩ		0.22		@TA=25 ° C
Supply Voltage	VCC	V	4.5	5	5.5	
Power Consumption Current	IC	mA		8	10	
Reference Voltage Output	Vref	V	2.48	2.5	2.52	
Output Voltage Range	Vout -Vref	V	-2		2	
Quiescent Output @IP=0	VOE	mV	-5		5	Vout-Vref @ Vref=2.5V
Reference Voltage Temp Drift	TCVref	ppm/ ° C	-170		170	-40 ° C to 105 ° C
Quiescent Output Temp Drift	TCVOE	mV/ ° C	-0.075		0.075	-40 ° C to 105 ° C
Nominal Sensitivity	Gth	mV/A		10		800mV@IPN
Sensitivity Error	ε G	%	-0.5		0.5	
Sensitivity Temp Drift @G	TCG	ppm/ ° C	-200		200	
Linearity 0-IPN	ε L	% of	-0.4		0.4	@0-IPN
Remanence	IOM	A	-0.2		0.2	
Response Time 90% of IPN	tr	μs			2.5	@50A/μs
Bandwidth (-3dB)	BW	kHz		250		
Accuracy @ IPN @TA=25 ° C	X	% of IPN	-1		1	
Accuracy @ IPN @TA=-40-105 ° C	X	% of IPN	-2.5		2.5	
Insulation Voltage	KV			2		
Overcurrent Copper Operating Temp	° C				120	

**YC0V100LSR5 Electrical Parameters @25°C, Vcc=5V, RL=10KΩ**

Parameter	Symbol	Unit	Min	Typ	Max	Remarks
Nominal Input Current	IPN	A		100		
Max Measurable Current	IPM	A	-250		250	VCC > 4.6V
Overcurrent Copper Resistance	RP	mΩ		0.22		@TA=25 ° C
Supply Voltage	VCC	V	4.5	5	5.5	
Power Consumption Current	IC	mA		8	10	
Reference Voltage Output	Vref	V	2.48	2.5	2.52	
Output Voltage Range	Vout -Vref	V	-2		2	
Quiescent Output @IP=0	VOE	mV	-5		5	Vout-Vref @ Vref=2.5V
Reference Voltage Temp Drift	TCVref	ppm/ ° C	-170		170	-40 ° C to 105 ° C
Quiescent Output Temp Drift	TCVOE	mV/ ° C	-0.075		0.075	-40 ° C to 105 ° C
Nominal Sensitivity	Gth	mV/A		8		800mV@IPN
Sensitivity Error	ε G	%	-0.5		0.5	
Sensitivity Temp Drift @G	TCG	ppm/ ° C	-200		200	
Linearity 0-IPN	ε L	% of	-0.4		0.4	@0-IPN
Remanence	IOM	A	-0.2		0.2	
Response Time 90% of IPN	tr	μs			2.5	@50A/μs
Bandwidth (-3dB)	BW	kHz		250		
Accuracy @ IPN @TA=25 ° C	X	% of IPN	-1		1	
Accuracy @ IPN @TA=-40-105 ° C	X	% of IPN	-2.5		2.5	
Insulation Voltage	KV			2		
Overcurrent Copper Operating Temp	° C				120	

**YC0V120LSR5 Electrical Parameters @25°C, Vcc=5V, RL=10KΩ**

Parameter	Symbol	Unit	Min	Typ	Max	Remarks
Nominal Input Current	IPN	A		120		
Max Measurable Current	IPM	A	-300		300	VCC > 4.6V
Overcurrent Copper Resistance	RP	mΩ		0.22		@TA=25 ° C
Supply Voltage	VCC	V	4.5	5	5.5	
Power Consumption Current	IC	mA		8	10	
Reference Voltage Output	Vref	V	2.48	2.5	2.52	
Output Voltage Range	Vout -Vref	V	-2		2	
Quiescent Output @IP=0	VOE	mV	-5		5	Vout-Vref @ Vref=2.5V
Reference Voltage Temp Drift	TCVref	ppm/ ° C	-170		170	-40 ° C to 105 ° C
Quiescent Output Temp Drift	TCVOE	mV/ ° C	-0.075		0.075	-40 ° C to 105 ° C
Nominal Sensitivity	Gth	mV/A		6.67		800mV@IPN
Sensitivity Error	ε G	%	-0.5		0.5	
Sensitivity Temp Drift @G	TCG	ppm/ ° C	-200		200	
Linearity 0-IPN	ε L	% of	-0.4		0.4	@0-IPN
Remanence	IOM	A	-0.2		0.2	
Response Time 90% of IPN	tr	μs			2.5	@50A/μs
Bandwidth (-3dB)	BW	kHz		250		
Accuracy @ IPN @TA=25 ° C	X	% of IPN	-1		1	
Accuracy @ IPN @TA=-40-105 ° C	X	% of IPN	-2.5		2.5	
Insulation Voltage	KV			2		
Overcurrent Copper Operating Temp	° C				120	